Diode Semiconductor Device - Page 1 of 1



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	Material:
Glass	
Overall Le	•
0.200 inch	
Terminal L	
0.500 inch	
Overall Di	
0.090 inch	
End Appli	
Trng devic	
Joint Elec	tronic Device Engineering Council/jedec/case Outline Designation
Do-35	
Mounting	Method:
Terminal	
Features F	Provided:
Hermetical	lly sealed case
Semicond	luctor Material:
Silicon	
Voltage Ra	ating In Volts Per Characteristic:
85.0 rever	rse voltage, peak
Current Ra	ating Per Characteristic:
10.00 millia	amperes source cutoff current preset
Terminal 1	Type And Quantity:
2 uninsulat	ted wire lead
Shelf Life:	
N/a	
Unit Of Me	easure:
Demilitaria	zation:
No	
Fiig:	
A110a0	